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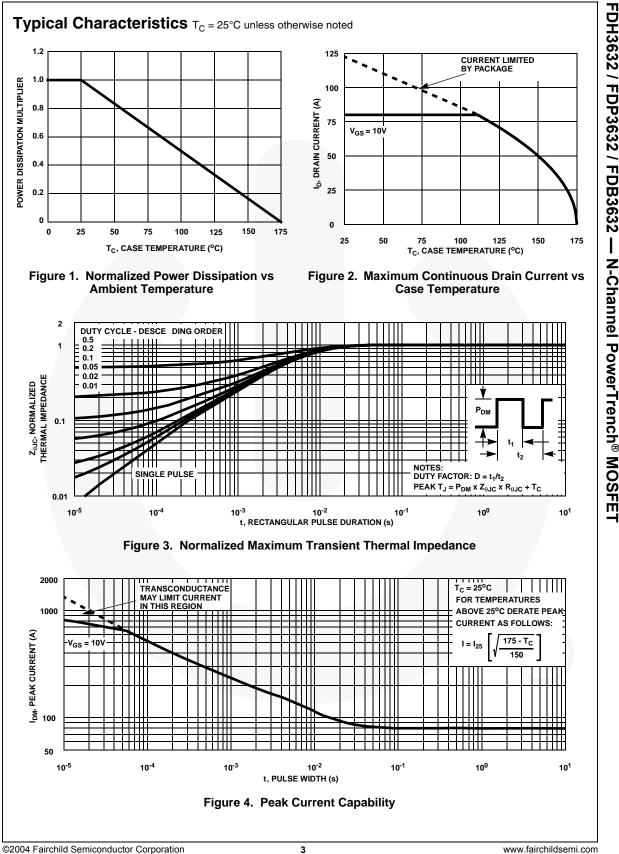


$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case, Max. TO-220, D ² -PAK, TO-247	0.48	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to Ambient, Max. TO-220 (Note 2)	62	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to Ambient D ² -PAK, Max. 1in ² copper pad area	43	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to Ambient, Max. TO-247 (Note 2)	30	°C/W

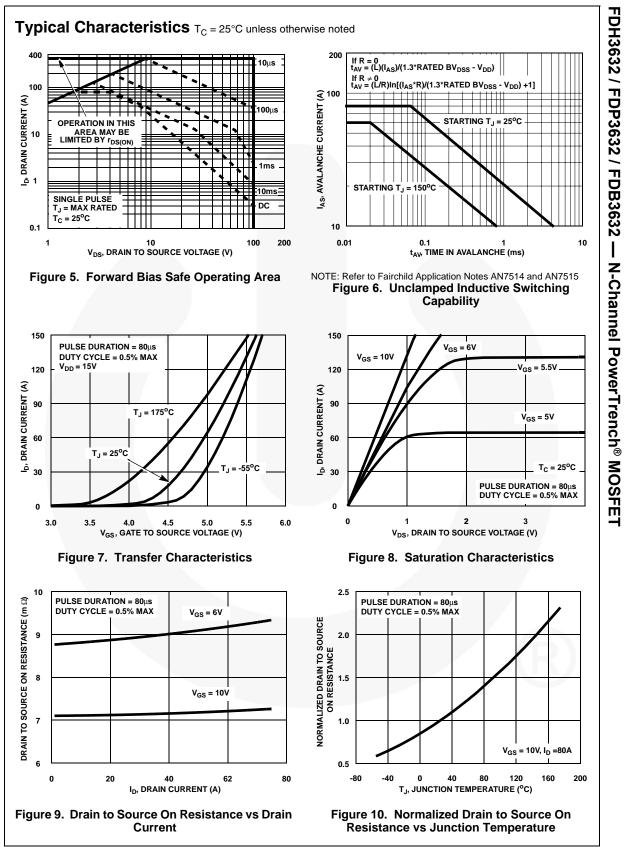
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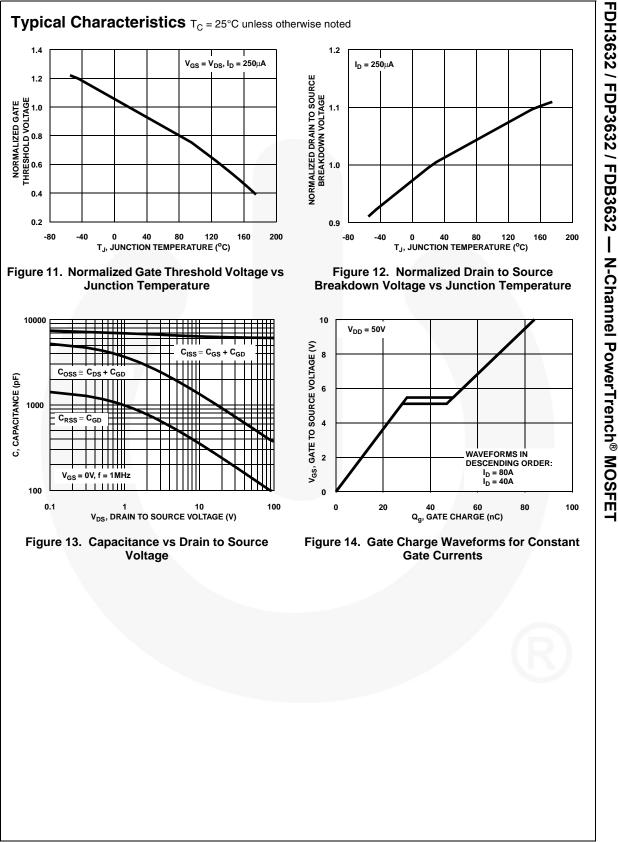
Device Marking FDB3632		Device	Package	R	Reel Size	Таре	Width	Quantity	
		FDB3632	D ² -PAK	330 mm		24 mm		800 units	
FDP3632		FDP3632	TO-220 Tube		N/A		50 units		
FDH3632 FD		FDH3632	TO-247 Tube		N/A		30 units		
Electric	al Char	acteristics T _C = 25°C	unless otherwi	se no	ted				
Symbol		Parameter	Test Conditions		Min	Тур	Max	Units	
Off Chara	cteristic	S							
B _{VDSS}	Drain to S	ource Breakdown Voltage	I _D = 250μA	, Vas	= 0V	100	-	-	V
I _{DSS}			V _{DS} = 80V				-	1	
	Zero Gate	e Voltage Drain Current	$V_{GS} = 0V$		$T_{C} = 150^{\circ}C$	-	-	250	μA
I _{GSS}	Gate to S	ource Leakage Current	V _{GS} = ±20\	/	, č	-	-	±100	nA
On Chara	cteristics	6							
V _{GS(TH)}		ource Threshold Voltage	$V_{CC} = V_{DC}$	ln =	250uA	2	-	4	V
r _{DS(ON)}				$V_{GS} = V_{DS}, I_D = 250\mu A$ $I_D = 80A, V_{GS} = 10V$			0.0075	0.009	Ω
	Drain to S	ource On Resistance		$I_{\rm D}$ =40A, $V_{\rm GS}$ = 6V,			0.009	0.015	
				I _D =80A, V _{GS} =10V, T _C =175°C			0.018	0.022	
Dynamic	Characte	eristics							
C _{ISS}	Input Cap	acitance				-	6000	-	pF
C _{OSS}	Output Ca	apacitance	V _{DS} = 25V f = 1MHz	V _{GS}	= 0V,	-	820	-	pF
C _{RSS}	Reverse 7	Transfer Capacitance	1 = 1101112			-	200	-	pF
Q _{g(TOT)}	Total Gate	e Charge at 10V	$V_{GS} = 0V t$	o 10V		-	84	110	nC
Q _{g(TH)}	Threshold	Gate Charge	$V_{GS} = 0V t$	5 2V	V _{DD} = 50V	-	11	14	nC
Q _{gs}	Gate to S	ource Gate Charge			I _D = 80A	-	30	-	nC
Q _{gs2}	Gate Cha	rge Threshold to Plateau			l _g = 1.0mA	-	20	-	nC
Q _{gd}	Gate to D	rain "Miller" Charge				-	20	-	nC
Resistive	Switchir	g Characteristics (V	_{GS} = 10V)						
t _{ON}	Turn-On T						-	102	ns
t _{d(ON)}	Turn-On E	Delay Time				-	30		ns
t _r	Rise Time	9	V _{DD} = 50V,	$V_{DD} = 50V, I_D = 80A$ $V_{GS} = 10V, R_{GS} = 3.6\Omega$		-	39	-	ns
t _{d(OFF)}	Turn-Off	Delay Time				-	96	-	ns
	Fall Time					-	46	-	ns
t _f	Turn-Off T	ime				-	-	213	ns
t _f t _{OFF}								6	~
t _{OFF}		le Characteristics			I _{SD} = 80A		1	1.25	
t _{OFF} Drain-Sou	urce Dioc		I _{SD} = 80A			-	-	1.25	V
t _{OFF} Drain-Sou	urce Dioc	le Characteristics Drain Diode Voltage	I _{SD} = 80A I _{SD} = 40A			-	-	1.23	V
t _{OFF}	Source to		I _{SD} = 40A	dl _{SD} /d	dt= 100A/µs		-		

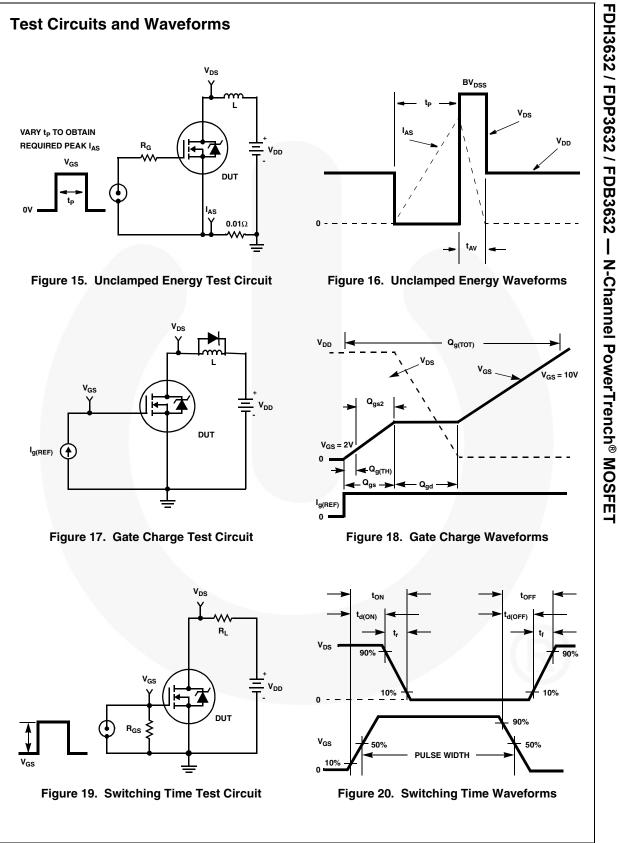


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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-263 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeter square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

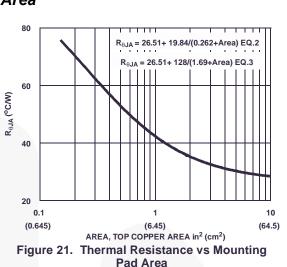
$$R_{\theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
(EQ. 2)

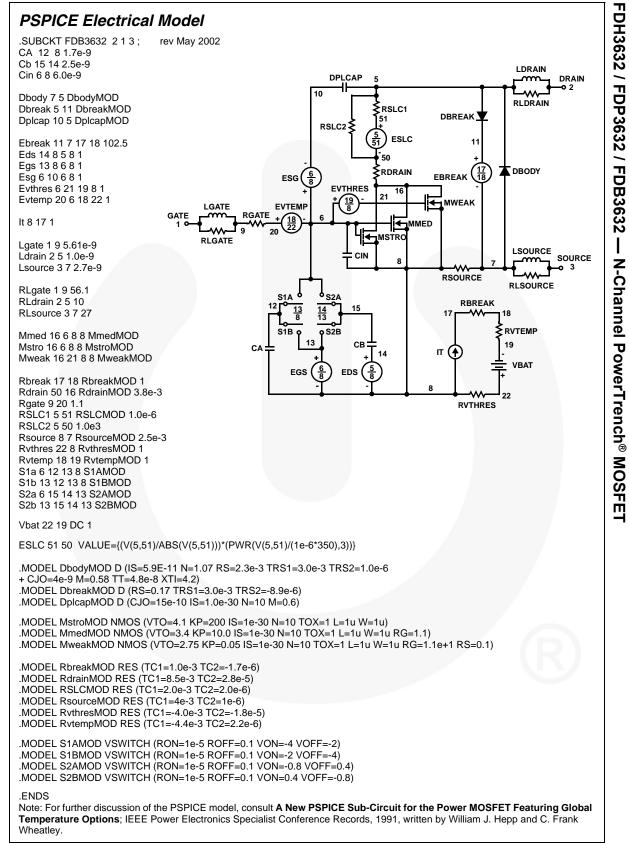
$$R_{\theta JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
 (EQ. 3)

Area in Centimeter Squared

Are

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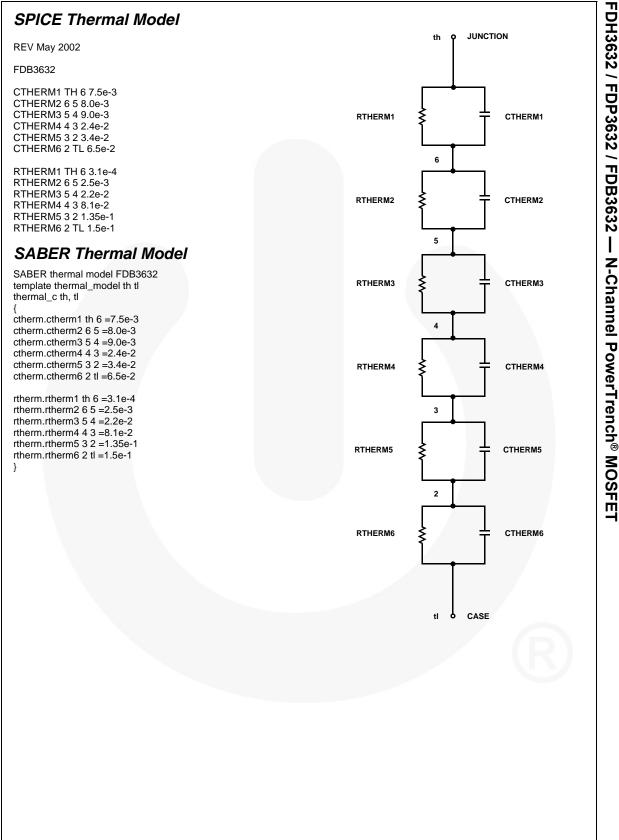


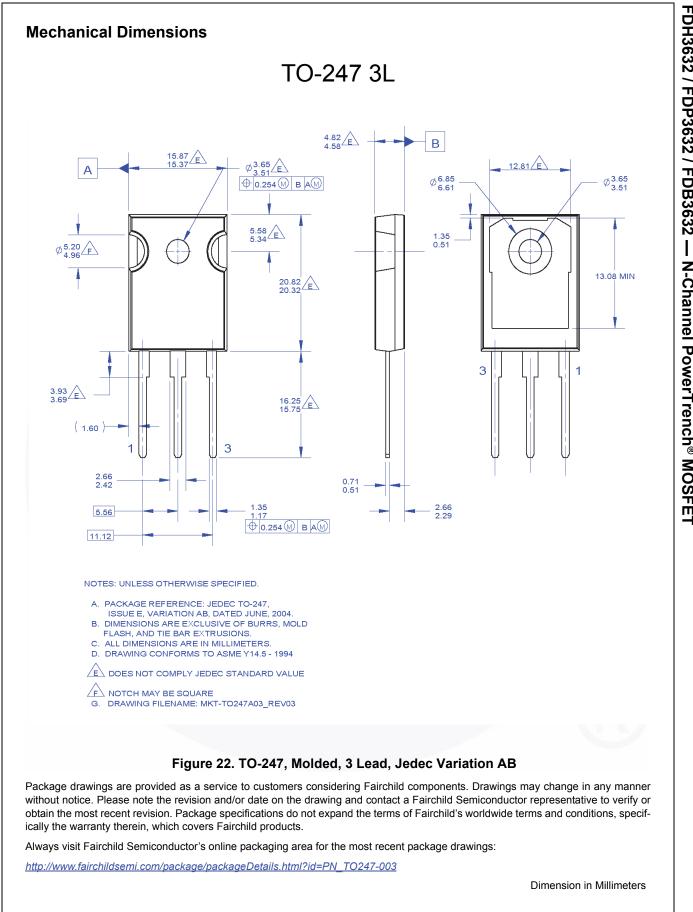


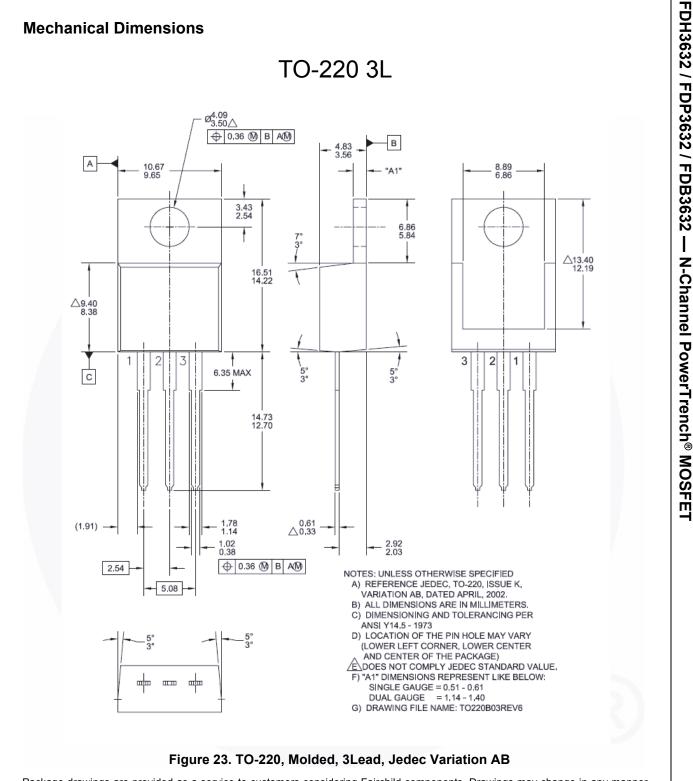
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SABER Electrical Model DH3632 / FDP3632 / FDB3632 — REV May 2002 template FDB3632 n2,n1,n3 electrical n2,n1,n3 var i iscl dp..model dbodymod = (isl=5.9e-11,nl=1.07,rs=2.3e-3,trs1=3.0e-3,trs2=1.0e-6,cjo=4e-9,m=0.58,tt=4.8e-8,xti=4.2) dp..model dbreakmod = (rs=0.17, trs1=3.0e-3, trs2=-8.9e-6)dp..model dplcapmod = (cjo=15e-10,isl=10.0e-30,nl=10,m=0.6) m..model mstrongmod = (type=_n,vto=4.1,kp=200,is=1e-30, tox=1) m..model mmedmod = $(type=_n, vto=3.4, kp=10.0, is=1e-30, tox=1)$ m..model mweakmod = (type=_n,vto=2.75,kp=0.05,is=1e-30, tox=1,rs=0.1) sw_vcsp..model s1amod = (ron=1e-5,roff=0.1,von=-4,voff=-2) LDRAIN sw_vcsp..model s1bmod = (ron=1e-5,roff=0.1,von=-2,voff=-4) DPLCAP DRAIN sw_vcsp..model s2amod = (ron=1e-5,roff=0.1,von=-0.8,voff=0.4) 10 sw_vcsp..model s2bmod = (ron=1e-5,roff=0.1,von=0.4,voff=-0.8) RLDRAIN c.ca n12 n8 = 1.7e-9 RSLC1 51 c.cb n15 n14 = 2.5e-9 RSLC2 c.cin n6 n8 = 6.0e-9 Ð ISCL dp.dbody n7 n5 = model=dbodymod DBREAK 50 **N-Channel PowerTrench® MOSFET** dp.dbreak n5 n11 = model=dbreakmod RDRAIN <u>6</u> 8 dp.dplcap n10 n5 = model=dplcapmod ESG 11 DBODY EVTHRES 16 21 spe.ebreak n11 n7 n17 n18 = 102.5 (<u>19</u> 8 ł MWEAK LGATE EVTEMP spe.eds n14 n8 n5 n8 = 1 RGATE GATE \mathbf{m} 18 22 EBREAK spe.egs n13 n8 n6 n8 = 1 q 20 Ч⋸ spe.esg n6 n10 n6 n8 = 1 MSTRO RLGATE spe.evthres n6 n21 n19 n8 = 1 18 LSOURCE CIN spe.evtemp n20 n6 n18 n22 = 1 SOURCE я 0 RSOURCE \mathbf{w} i.it n8 n17 = 1 RLSOURCE l.lgate n1 n9 = 5.61e-9 RBREAK <u>14</u> 13 l.ldrain n2 n5 = 1.0e-9 17 18 l.lsource n3 n7 = 2.7e-9 ₹ RVTFMP o S2B 13 СВ 19 res.rlgate n1 n9 = 56.1 CA ΙТ (♠` 14 res.rldrain n2 n5 = 10VBAT res.rlsource n3 n7 = 27 <u>6</u> 8 EGS EDS 8 m.mmed n16 n6 n8 n8 = model=mmedmod, l=1u, w=1u 22 m.mstrong n16 n6 n8 n8 = model=mstrongmod, l=1u, w=1u RVTHRES m.mweak n16 n21 n8 n8 = model=mweakmod, l=1u, w=1u res.rbreak n17 n18 = 1, tc1=1.0e-3,tc2=-1.7e-6 res.rdrain n50 n16 = 3.8e-3, tc1=8.5e-3,tc2=2.8e-5 res.rgate n9 n20 = 1.1 res.rslc1 n5 n51 = 1.0e-6, tc1=2.0e-3,tc2=2.0e-6 res.rslc2 n5 n50 = 1.0e3 res.rsource n8 n7 = 2.5e-3, tc1=4e-3,tc2=1e-6 res.rvthres n22 n8 = 1, tc1=-4.0e-3,tc2=-1.8e-5 res.rvtemp n18 n19 = 1, tc1=-4.4e-3,tc2=2.2e-6 sw vcsp.s1a n6 n12 n13 n8 = model=s1amod sw_vcsp.s1b n13 n12 n13 n8 = model=s1bmod sw_vcsp.s2a n6 n15 n14 n13 = model=s2amod sw_vcsp.s2b n13 n15 n14 n13 = model=s2bmod v.vbat n22 n19 = dc=1 equations { i (n51->n50) +=iscl iscl: v(n51,n50) = ((v(n5,n51)/(1e-9+abs(v(n5,n51))))*((abs(v(n5,n51)*1e6/350))**3))}

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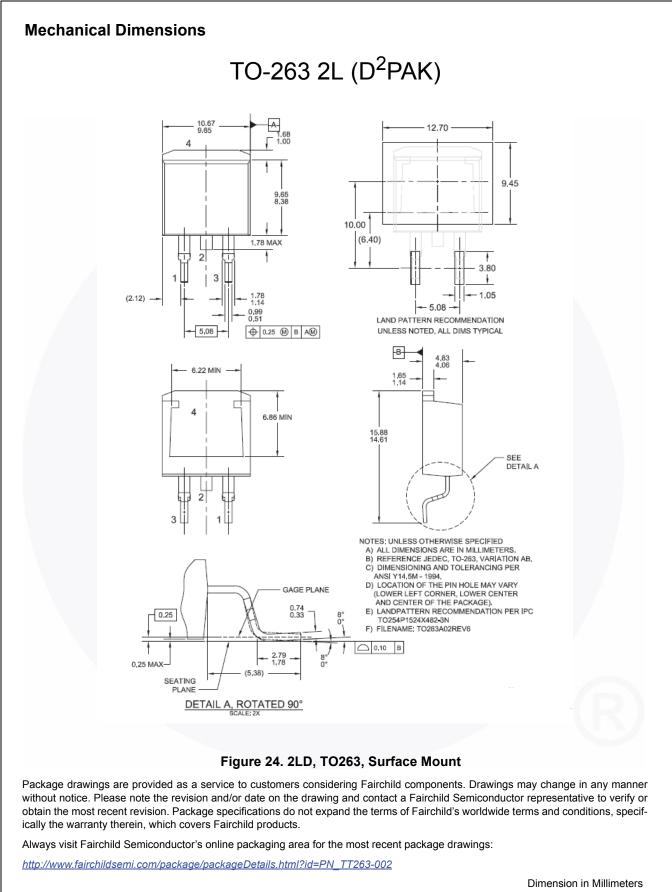


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Dimension in Millimeters





No Identification Needed

Obsolete

Full Production

Not In Production

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Rev. 166

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